

# isc N-Channel MOSFET Transistor

# STD8NM50N

<ul> <li>Drain So</li> <li>: V<sub>DSS</sub>= 5</li> <li>Static Dr</li> <li>: R<sub>DS(on)</sub> =</li> <li>100% av</li> <li>Minimum performa</li> </ul>	irrent $-I_D$ = 5A@ T <sub>C</sub> =25°C urce Voltage- i00V(Min) ain-Source On-Resistance = 790m $\Omega$ (Max) alanche tested in Lot-to-Lot variations for robust device unce and reliable operation	DPAK DPAK DPAK C 0.5 C 0		
	E MAXIMUM RATINGS(Ta=25°C)			
SYMBOL	PARAMETER	VALUE		D
V <sub>DSS</sub>	Drain-Source Voltage	500	V	
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±25	V	
ID	Drain Current-Continuous	5	A	F F F F F
PD	Total Dissipation @T <sub>C</sub> =25℃	45	W	G
TJ	Max. Operating Junction Temperature	150	°C	mm
T <sub>stg</sub>	Storage Temperature	-55~150	°C	DIM MIN MAX A 6.40 6.60 B 5.20 5.40
THERMAL	CHARACTERISTICS			C         1.15         1.35           D         5.70         6.10           F         0.65           G         0.75
SYMBOL	PARAMETER	МАХ	UNIT	H 2.10 2.50 J 2.10 2.40
Rth j-c	Thermal Resistance, Junction to Case	2.78	°C/W	K         0.40         0.60           L         0.90         1.10           Q         9.90         10.1



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	500		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.25mA	2	4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 2.5A		790	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = Max rating; V <sub>DS</sub> = Max rating; T <sub>j</sub> = 125°C		1 100	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 5A; V <sub>GS</sub> =0		1.5	V

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